

# TPS3610U18, TPS3610T50 BATTERY-BACKUP SUPERVISORS FOR RAM RETENTION

SLVS327B – DECEMBER 2000 – REVISED DECEMBER 2002

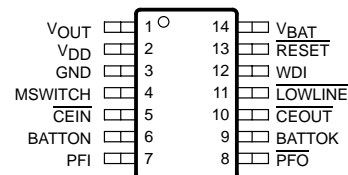
## features

- Supply Current of 40  $\mu$ A (Max)
- Battery Supply Current of 100 nA (Max)
- Precision Supply-Voltage Monitor, 1.8 V, 5 V; Other Options on Request
- Watchdog Timer With 800-ms Time-Out
- Backup-Battery Voltage Can Exceed  $V_{DD}$
- Power-On Reset Generator With Fixed 100-ms Reset Delay Time
- Battery-OK Output
- Voltage Monitor for Power-Fail or Low-Battery Monitoring
- Manual Switchover to Battery-Backup Mode
- Chip-Enable Gating . . . 3 ns (at  $V_{DD} = 5$  V)  
Max Propagation Delay
- Battery-Freshness Seal
- 14-pin TSSOP Package
- Temperature Range . . .  $-40^{\circ}\text{C}$  to  $85^{\circ}\text{C}$

## typical applications

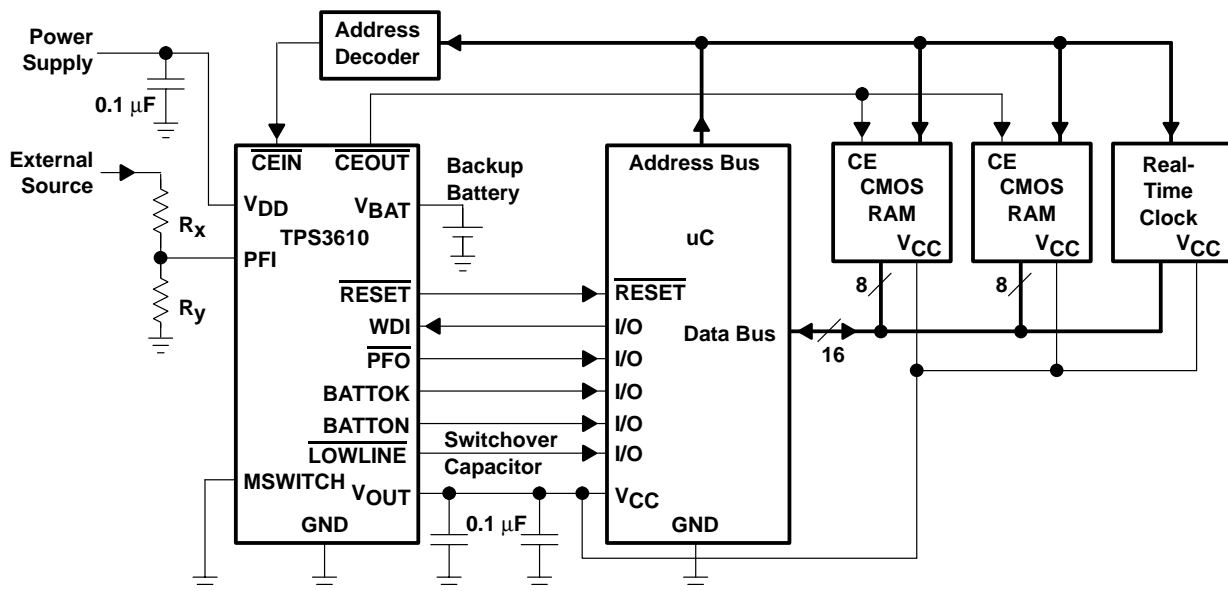
- Fax Machines
- Set-Top Boxes
- Advanced Voice Mail Systems
- Portable Battery-Powered Equipment
- Computer Equipment
- Advanced Modems
- Automotive Systems
- Portable Long-Time Monitoring Equipment
- Point of Sale Equipment

TPS3610  
TSSOP (PW) Package  
(TOP VIEW)



ACTUAL SIZE  
(5,10mm x 6,60mm)

## typical operating circuit



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**TEXAS  
INSTRUMENTS**

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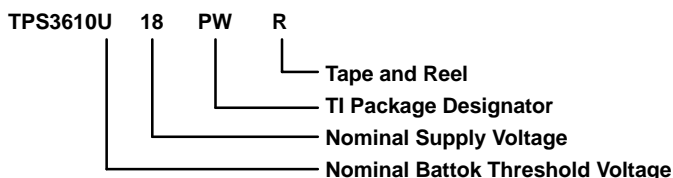
## description

The TPS3610 family of supervisory circuits monitors and controls processor activity by providing backup-battery switchover for data retention of CMOS RAM. Other features include an additional power-fail comparator, low-line indication, watchdog function, battery-status indicator, manual switchover, and write protection for CMOS RAM.

The TPS3610 family allow usage of 3-V or 3.6-V lithium batteries as the backup supply in systems with, e.g.,  $V_{DD} = 1.8$  V. During power-on,  $\overline{RESET}$  is asserted when the supply voltage ( $V_{DD}$  or  $V_{BAT}$ ) becomes higher than 1.1 V. Thereafter, the supply-voltage supervisor monitors  $V_{DD}$  and keeps  $\overline{RESET}$  output active as long as  $V_{DD}$  remains below the threshold voltage  $V_{IT}$ . An internal timer delays the return of the output to the inactive state (high) to ensure proper system reset. The delay time starts after  $V_{DD}$  has risen above the threshold voltage  $V_{IT}$ . When the supply voltage drops below the threshold voltage  $V_{IT}$ , the output becomes active (low) again.

The product spectrum is designed for supply voltages of 1.8 V and 5 V. The circuits are available in a 14-pin TSSOP package. TPS3610 devices are characterized for operation over a temperature range of  $-40^{\circ}\text{C}$  to  $85^{\circ}\text{C}$ .

## standard and application-specific versions (see Note 1)



APPLICATION-SPECIFIC VERSIONS, NOMINAL SUPPLY AND BATTOK VOLTAGE			
$T_A$	NOMINAL SUPPLY VOLTAGE, $V_{DD}(\text{NOM})$ (V)	NOMINAL BATTOK THRESHOLD VOLTAGE, $V_{IT}(\text{BOK})$ (V)	PACKAGED DEVICES TSSOP (PW) <sup>†</sup>
$-40^{\circ}\text{C}$ to $85^{\circ}\text{C}$	1.8	1.6	TPS3610U18PWR
	5	2.4	TPS3610T50PWR

<sup>†</sup> The PW package is only available taped and reeled (indicated by the R suffix on the device type).

NOTE 1: For other NOMINAL and BATTOK voltage versions, contact your local TI sales office for availability and order lead time.



# TPS3610U18, TPS3610T50 BATTERY-BACKUP SUPERVISORS FOR RAM RETENTION

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## TRUTH TABLES

INPUTS				OUTPUTS				
$V_{DD} > V_{LL}$	$V_{DD} > V_{IT}$	$V_{DD} > V_{BAT}$	MSWITCH	$V_{OUT}$	BATTON	$\overline{LOWLINE}$	$\overline{RESET}$	$\overline{CEOUT}$
0	0	0	0	V <sub>BAT</sub>	1	0	0	DIS
0	0	0	0	V <sub>BAT</sub>	1	0	0	DIS
0	0	0	1	V <sub>BAT</sub>	1	0	0	DIS
0	0	0	1	V <sub>BAT</sub>	1	0	0	DIS
0	0	1	0	V <sub>DD</sub>	0	0	0	DIS
0	0	1	0	V <sub>DD</sub>	0	0	0	DIS
0	0	1	1	V <sub>BAT</sub>	1	0	0	DIS
0	0	1	1	V <sub>BAT</sub>	1	0	0	DIS
0	1	0	0	V <sub>DD</sub>	0	0	1	DIS
0	1	0	0	V <sub>DD</sub>	0	0	1	EN
0	1	0	1	V <sub>BAT</sub>	1	0	1	DIS
0	1	0	1	V <sub>BAT</sub>	1	0	1	EN
0	1	1	0	V <sub>DD</sub>	0	0	1	DIS
0	1	1	0	V <sub>DD</sub>	0	0	1	EN
0	1	1	1	V <sub>BAT</sub>	1	0	1	DIS
0	1	1	1	V <sub>BAT</sub>	1	0	1	EN
1	1	0	0	V <sub>DD</sub>	0	1	1	DIS
1	1	0	0	V <sub>DD</sub>	0	1	1	EN
1	1	0	1	V <sub>BAT</sub>	1	1	1	DIS
1	1	0	1	V <sub>BAT</sub>	1	1	1	EN
1	1	1	0	V <sub>DD</sub>	0	1	1	DIS
1	1	1	0	V <sub>DD</sub>	0	1	1	EN
1	1	1	1	V <sub>BAT</sub>	1	1	1	DIS
1	1	1	1	V <sub>BAT</sub>	1	1	1	EN

BATTOK		POWER-FAIL		CHIP-ENABLE	
$V_{BAT} > V_{BOK}$	BATTOK	$PFI > V_{(PFI)}$	$\overline{PFO}$	$\overline{CEIN}$	$\overline{CEOUT}$
0	0	0	0	0	0
1	1	1	1	1	1

Condition:  $V_{DD} > V_{IT}$

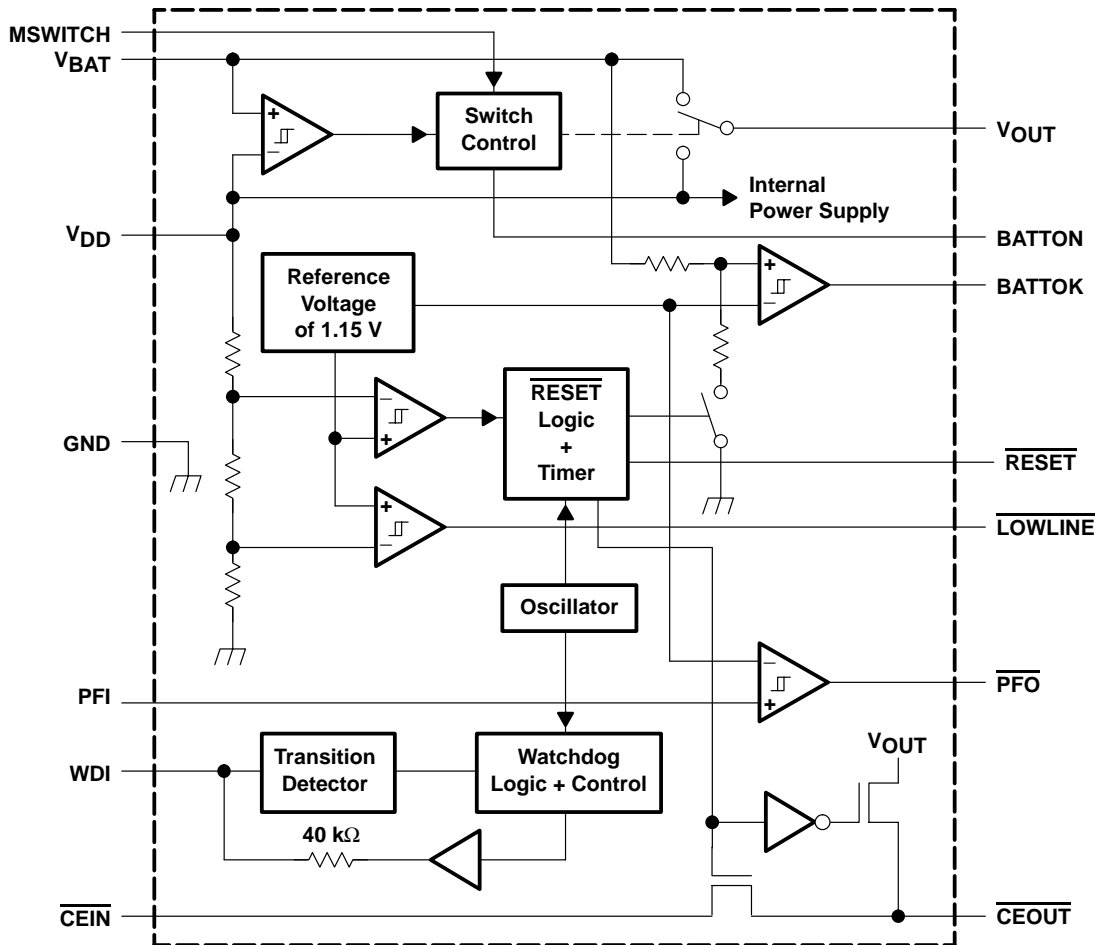
Condition:  $V_{DD} > V_{DDmin}$

Condition: Enabled

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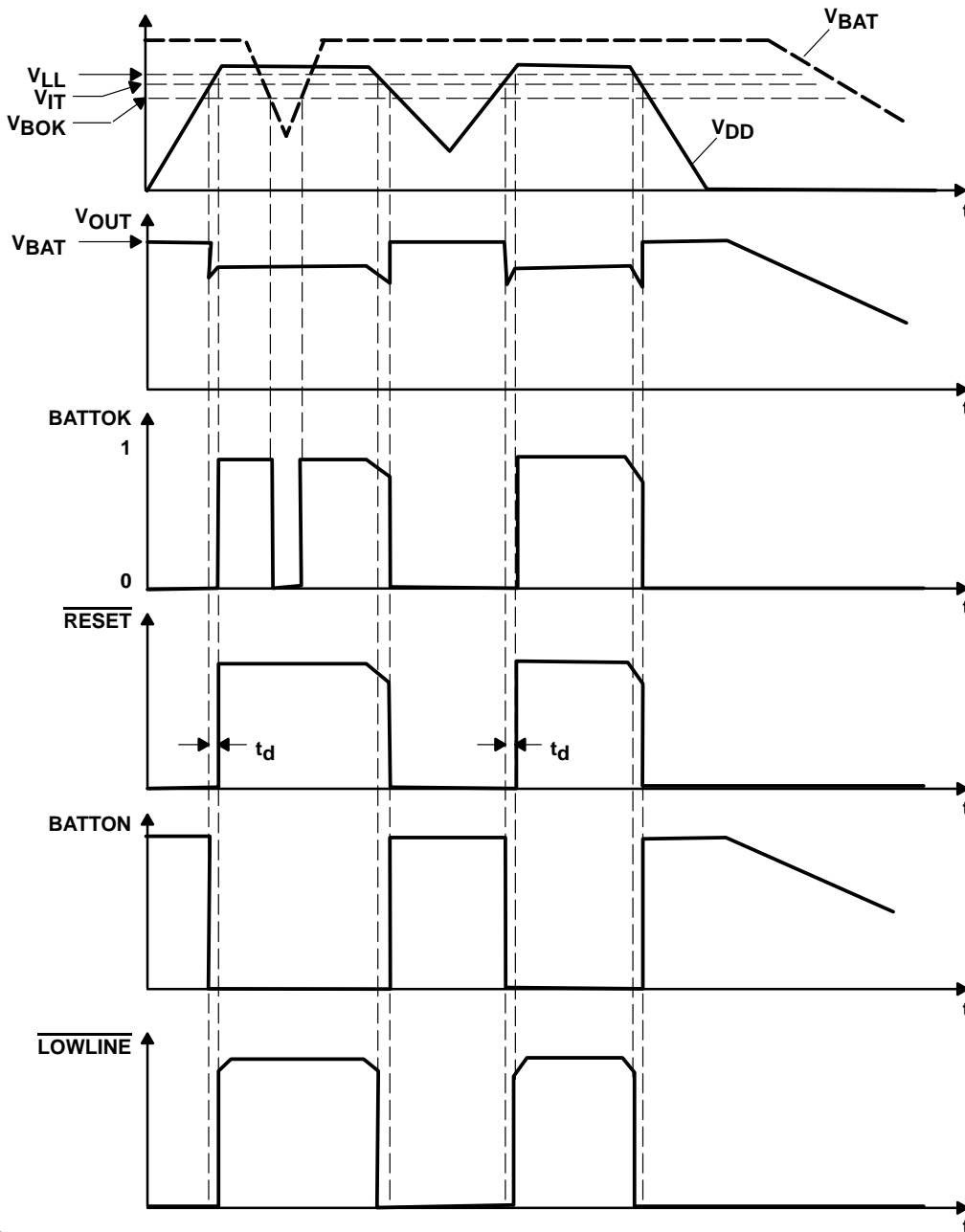
## functional block diagram



# TPS3610U18, TPS3610T50 BATTERY-BACKUP SUPERVISORS FOR RAM RETENTION

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timing diagram



† MSWITCH = 0

Timing diagram shown under operation, not in freshness seal mode.

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## Terminal Functions

TERMINAL NAME	NO.	I/O	DESCRIPTION
BATTOK	9	O	Battery status output
BATTON	6	O	Logic output/external bypass switch driver output
$\overline{\text{CEIN}}$	5	I	Chip-enable input
$\overline{\text{CEOUT}}$	10	O	Chip-enable output
GND	3	I	Ground
$\overline{\text{LOWLINE}}$	11	O	Early power-fail warning output
MSWITCH	4	I	Manual switch to force device into battery-backup mode
V <sub>OUT</sub>	1	O	Supply output
PFI	7	I	Power-fail comparator input
$\overline{\text{PFO}}$	8	O	Power-fail comparator output
$\overline{\text{RESET}}$	13	O	Active-low reset output
V <sub>BAT</sub>	14	I	Backup-battery input
V <sub>DD</sub>	2	I	Input supply voltage
WDI	12	I	Watchdog timer input

## detailed description

### battery freshness seal

The battery freshness seal of the TPS3610 family disconnects the backup battery from internal circuitry until it is needed. This function ensures that the backup battery connected to V<sub>BAT</sub> is fresh when the final product is put to use. The following steps explain how to enable the freshness seal mode:

1. Connect V<sub>BAT</sub> (V<sub>BAT</sub> > V<sub>BATmin</sub>)
2. Ground  $\overline{\text{PFO}}$
3. Connect PFI to V<sub>DD</sub> (PFI = V<sub>DD</sub>)
4. Connect V<sub>DD</sub> to power supply (V<sub>DD</sub> > V<sub>IT</sub>) and keep connected for 5 ms < t < 35 ms

The battery freshness seal mode is disabled by the positive-going edge of  $\overline{\text{RESET}}$  when V<sub>DD</sub> is applied.

### BATTOK output

BATTOK is a logic feedback of the device to indicate the status of the backup battery. The supervisor checks the battery voltage every 200 ms with a voltage divider load of approximately 100 kΩ and a measurement cycle on-time of 25 μs. The measurement cycle starts after the reset is released. If the battery voltage V<sub>BAT</sub> is below the negative-going threshold voltage V<sub>IT(BOK)</sub>, the indicator BATTOK does a high-to-low transition. Otherwise it retains its status to V<sub>DD</sub> level.

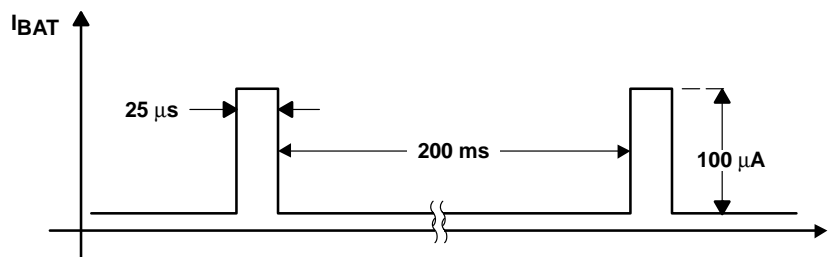


Figure 1. BATTOK Timing



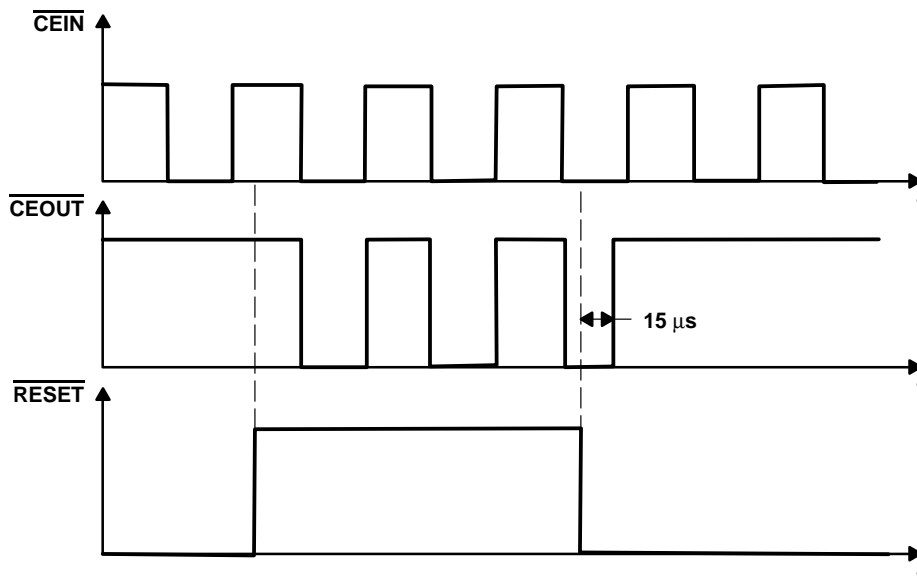
**detailed description (continued)**

**chip-enable signal gating**

The internal gating of chip-enable signals, CE, prevents erroneous data from corrupting CMOS RAM during an undervoltage condition. The TPS3610 use a series transmission gate from  $\overline{CEIN}$  to  $\overline{CEOUT}$ . During normal operation (reset not asserted), the CE transmission gate is enabled and passes all CE transitions. When reset is asserted, this path becomes disabled, preventing erroneous data from corrupting the CMOS RAM. The short CE propagation delay from  $\overline{CEIN}$  to  $\overline{CEOUT}$  enables TPS3610 devices to be used with most processors.

The CE transmission gate is disabled and  $\overline{CEIN}$  is high-impedance (disable mode) while reset is asserted. During a power-down sequence, when  $V_{DD}$  crosses the reset threshold, the CE transmission gate is disabled and  $\overline{CEIN}$  immediately becomes high impedance if the voltage at  $\overline{CEIN}$  is high. If  $\overline{CEIN}$  is low while reset is asserted, the CE transmission gate is disabled at the same time  $\overline{CEIN}$  goes high, or 15  $\mu$ s after  $\overline{RESET}$  asserts, whichever occurs first. This allows the current write cycle to complete during power-down. When the CE transmission gate is enabled, the impedance of  $\overline{CEIN}$  appears as a resistor in series with the load at  $\overline{CEOUT}$ . The overall device propagation delay through the CE transmission gate depends on  $V_{OUT}$ , the source impedance of the device connected to  $\overline{CEIN}$  and the load at  $\overline{CEOUT}$ . To achieve minimum propagation delay, the capacitive load at  $\overline{CEOUT}$  should be minimized, and a low-output-impedance driver should be used.

During disable mode, the transmission gate is off and an active pullup connects  $\overline{CEOUT}$  to  $V_{OUT}$ . The pullup turns off when the transmission gate is enabled.



**Figure 2. Chip-Enable Timing**

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## detailed description (continued)

### power-fail comparator (PFI and PFO)

An additional comparator is provided to monitor voltages other than the nominal supply voltage. The power-fail-input (PFI) is compared with an internal voltage reference of 1.15 V. If the input voltage falls below the power-fail threshold  $V_{IT(PFI)}$  of typical 1.15 V, the power-fail output ( $\overline{PFO}$ ) goes low. If  $V_{IT(PFI)}$  goes above  $V_{(PFI)}$ , plus about 12-mV hysteresis, the output returns to high. By connecting two external resistors, it is possible to supervise any voltages above  $V_{(PFI)}$ . The sum of both resistors should be about 1 M $\Omega$ , to minimize power consumption and also to assure that the current in the PFI pin can be neglected compared with the current through the resistor network. The tolerance of the external resistors should be not more than 1% to ensure minimal variation of sensed voltage. If the power-fail comparator is unused, PFI should be connected to ground and  $\overline{PFO}$  left unconnected.

### LOWLINE

The lowline comparator monitors  $V_{DD}$  with a threshold voltage typically 2% above the reset threshold ( $V_{IT}$ ). For normal operation ( $V_{DD}$  above the reset threshold),  $\overline{LOWLINE}$  is pulled to  $V_{DD}$ .  $\overline{LOWLINE}$  can be used to provide a nonmaskable interrupt (NMI) to the processor when power begins to fall. In most battery-operated portable systems, reserve energy in the battery provides enough time to complete the shutdown routine once the low-line warning is encountered and before reset asserts. If the system must also contend with a more rapid  $V_{DD}$  fall time, such as when the main battery is disconnected or a high-side switch is opened during normal operation, a capacitor can be used on the  $V_{DD}$  line to provide enough time for executing the shutdown routine. First, the worst-case settling time ( $t_{sd}$ ) required for the system to perform its shutdown routine needs to be defined. Then, using the worst-case load current ( $I_L$ ) that can be drained from the capacitor, and the minimum reset threshold voltage ( $V_{ITmin}$ ), the capacitor value ( $C_H$ ) can be calculated as follows:

$$C_H = \frac{I_L \times t_{sd}}{V_{ITmin} \times 0.012}$$

### BATTON

Most often BATTON is used as a gate drive for an external pass transistor for high-current applications. In addition, it can be used as a logic output to indicate the battery switchover status. BATTON is high when  $V_{OUT}$  is connected to  $V_{BAT}$ .

BATTON can be connected directly to the gate of a PMOS transistor (see Figure 3). No current-limiting resistor is required. If a PMOS transistor is used, it must be connected in the reverse of the traditional method (see Figure 3), which orients the body diode from  $V_{DD}$  to  $V_{OUT}$  and prevents the backup battery from discharging through the FET when its gate is high.

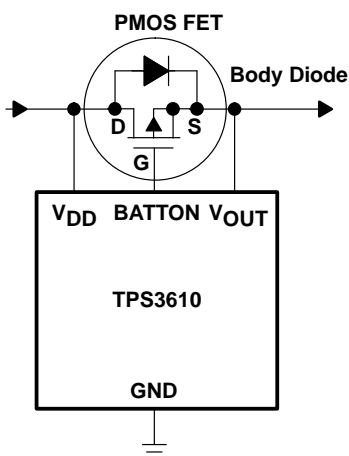


Figure 3. Driving an External MOSFET Transistor With BATTON



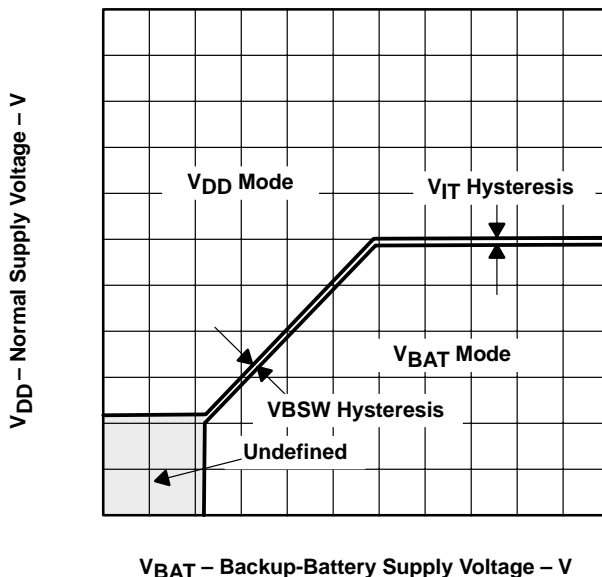
**detailed description (continued)**

**backup-battery switchover**

In case of a brownout or power failure, it may be necessary to preserve the contents of RAM. If a backup-battery is installed at  $V_{BAT}$ , the device automatically switches the connected RAM to backup power when  $V_{DD}$  fails. In order to allow the backup-battery (e.g., a 3.6-V lithium cell) to have a higher voltage than  $V_{DD}$ , these supervisors do not connect  $V_{BAT}$  to  $V_{OUT}$  when  $V_{BAT}$  is greater than  $V_{DD}$ .  $V_{BAT}$  only connects to  $V_{OUT}$  (through a 15- $\Omega$  switch) when  $V_{DD}$  falls below  $V_{IT}$  and  $V_{BAT}$  is greater than  $V_{DD}$ . When  $V_{DD}$  recovers, switchover is deferred either until  $V_{DD}$  crosses  $V_{BAT}$ , or until  $V_{DD}$  rises above the reset threshold  $V_{IT}$ .  $V_{OUT}$  connects to  $V_{DD}$  through a 1- $\Omega$  (max) PMOS switch when  $V_{DD}$  crosses the reset threshold.

**FUNCTION TABLE**

$V_{DD} > V_{BAT}$	$V_{DD} > V_{IT}$	$V_{OUT}$
1	1	$V_{DD}$
1	0	$V_{DD}$
0	1	$V_{DD}$
0	0	$V_{BAT}$



**Figure 4. Normal Supply Voltage vs Backup-Battery Supply Voltage**

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## detailed description (continued)

### manual switchover (MSWITCH)

While operating in the normal mode from  $V_{DD}$ , the device can be forced manually to operate in battery-backup mode by connecting MSWITCH to  $V_{DD}$ . Refer to Table 1 for different switchover modes.

**Table 1. Switchover Modes**

	MSWITCH	STATUS
$V_{DD}$ mode	GND	$V_{DD}$ mode
	$V_{DD}$	Switch to battery-backup mode
Battery-backup mode	GND	Battery-backup mode
	$V_{DD}$	Battery-backup mode

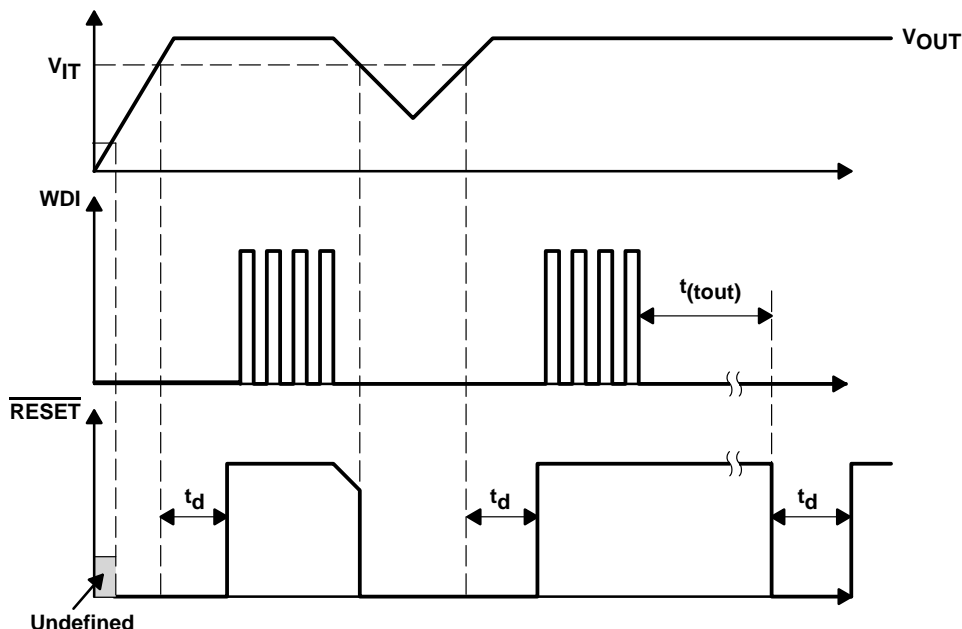
If the manual switchover feature is not used, MSWITCH *must* be connected to ground.

### watchdog

In a microprocessor- or DSP-based system, it is important not only to supervise the supply voltage, but also to ensure correct program execution. The task of a watchdog is to ensure that the program is not stalled in an indefinite loop. The microprocessor, microcontroller or DSP has to toggle the watchdog input within typically 0.8 s to avoid the occurrence of a time-out. Either a low-to-high or a high-to-low transition resets the internal watchdog timer. If the input is unconnected, the watchdog is disabled and is retriggered internally.

### saving current while using the watchdog

The watchdog input is internally driven low during the first 7/8 of the watchdog time-out period, then the input momentarily pulses high, resetting the watchdog counter. For minimum watchdog input current (minimum overall power consumption), WDI should be left low for the majority of the watchdog time-out period, and pulsed low-high-low once within 7/8 of the watchdog time-out period to reset the watchdog timer. If instead WDI is externally driven high for the majority of the timeout period, a current of, e.g.,  $5\text{ V}/40\text{ k}\Omega \approx 125\text{ }\mu\text{A}$ , can flow into WDI.



**Figure 5. Watchdog Timing**

# TPS3610U18, TPS3610T50

## BATTERY-BACKUP SUPERVISORS FOR RAM RETENTION

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### absolute maximum ratings over operating free-air temperature (unless otherwise noted)<sup>†</sup>

Supply voltage, $V_{DD}$ (see Note 2) .....	7 V
All other pins (see Note 2) .....	–0.3 V to 7 V
Continuous output current at $V_{OUT}$ , $I_{O(VOUT)}$ .....	400 mA
Continuous output current (all other pins) $I_O$ .....	±10 mA
Continuous total power dissipation .....	See Dissipation Rating Table
Operating free-air temperature range, $T_A$ .....	–40°C to 85°C
Storage temperature range, $T_{stg}$ .....	–65°C to 150°C
Lead temperature soldering 1,6 mm (1/16 inch) from case for 10 seconds .....	260°C

<sup>†</sup> Stresses beyond those listed under “absolute maximum ratings” may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under “recommended operating conditions” is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

NOTE 2: All voltage values are with respect to GND. For reliable operation the device must not be operated at 7 V for more than  $t=1000h$  continuously.

**DISSIPATION RATING TABLE**

PACKAGE	$T_A \leq 25^\circ\text{C}$ POWER RATING	DERATING FACTOR ABOVE $T_A = 25^\circ\text{C}$	$T_A = 70^\circ\text{C}$ POWER RATING	$T_A = 85^\circ\text{C}$ POWER RATING
PW	700 mW	5.6 mW/°C	448 mW	364 mW

### recommended operating conditions

	MIN	MAX	UNIT
Supply voltage, $V_{DD}$	1.65	5.5	V
Battery supply voltage, $V_{BAT}$	1.5	5.5	V
Input voltage, $V_I$	0	$V_{DD}+0.3$	V
High-level input voltage, $V_{IH}$	$0.7 \times V_{DD}$		V
Low-level input voltage, $V_{IL}$		$0.3 \times V_{DD}$	V
Continuous output current at $V_{OUT}$ , $I_O$		300	mA
Input transition rise and fall rate at WDI, MSWITCH, $\Delta t/\Delta V$		100	ns/V
Slew rate at $V_{DD}$ or $V_{BAT}$		1	V/ $\mu\text{s}$
Operating free-air temperature range, $T_A$	–40	85	°C



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electrical characteristics over recommended operating free-air temperature range (unless otherwise noted)

PARAMETER		TEST CONDITIONS		MIN	TYP	MAX	UNIT
V <sub>OH</sub>	High-level output voltage	$\overline{\text{RESET}}$ , BAT <sub>TOK</sub>	V <sub>DD</sub> = 1.8 V, I <sub>OH</sub> = -400 μA	V <sub>DD</sub> -0.2 V			V
			V <sub>DD</sub> = 3.3 V, I <sub>OH</sub> = -2 mA	V <sub>DD</sub> -0.4 V			
			V <sub>DD</sub> = 5 V, I <sub>OH</sub> = -3 mA				
	BAT <sub>TON</sub>	V <sub>OUT</sub> = 1.8 V, I <sub>OH</sub> = -400 μA	V <sub>OUT</sub> -0.2 V				
		V <sub>OUT</sub> = 3.3 V, I <sub>OH</sub> = -2 mA	V <sub>OUT</sub> -0.4 V				
		V <sub>OUT</sub> = 5 V, I <sub>OH</sub> = -3 mA					
	$\overline{\text{LOWLINE}}$ , P <sub>F0</sub>	V <sub>DD</sub> = 1.8 V, I <sub>OH</sub> = -20 μA	V <sub>DD</sub> -0.3 V				
		V <sub>DD</sub> = 3.3 V, I <sub>OH</sub> = -80 μA,	V <sub>DD</sub> -0.4 V				
		V <sub>DD</sub> = 5 V, I <sub>OH</sub> = -120 μA					
	$\overline{\text{CEOUT}}$ , Enable mode, CE <sub>IN</sub> = V <sub>OUT</sub>	V <sub>OUT</sub> = 1.8 V, I <sub>OH</sub> = -1 mA	V <sub>OUT</sub> -0.2 V				
		V <sub>OUT</sub> = 3.3 V, I <sub>OH</sub> = -2 mA	V <sub>OUT</sub> -0.3 V				
		V <sub>OUT</sub> = 5 V, I <sub>OH</sub> = -5 mA					
$\overline{\text{CEOUT}}$ , Disable mode	V <sub>OUT</sub> = 3.3 V, I <sub>OH</sub> = -0.5 mA	V <sub>OUT</sub> -0.4 V					
V <sub>OL</sub>	Low-level output voltage	$\overline{\text{RESET}}$ , $\overline{\text{PFO}}$ , BAT <sub>TOK</sub> , $\overline{\text{LOWLINE}}$	V <sub>DD</sub> = 1.8 V, I <sub>OL</sub> = 400 μA			0.2	V
			V <sub>DD</sub> = 3.3 V, I <sub>OL</sub> = 2 mA			0.4	
			V <sub>DD</sub> = 5 V, I <sub>OL</sub> = 3 mA				
	BAT <sub>TON</sub>	V <sub>OUT</sub> = 1.8 V, I <sub>OL</sub> = 500 μA			0.2		
		V <sub>OUT</sub> = 3.3 V, I <sub>OL</sub> = 3 mA			0.4		
		V <sub>OUT</sub> = 5 V, I <sub>OL</sub> = 5 mA					
	$\overline{\text{CEOUT}}$ , Enable mode, CE <sub>IN</sub> = 0 V	V <sub>OUT</sub> = 1.8 V, I <sub>OL</sub> = 1 mA			0.2		
		V <sub>OUT</sub> = 3.3 V, I <sub>OL</sub> = 2 mA			0.3		
		V <sub>OUT</sub> = 5 V, I <sub>OL</sub> = 5 mA					
Power-up reset voltage (see Note 3)		I <sub>OL</sub> = 20 μA,	V <sub>BAT</sub> > 1.1 V, OR V <sub>DD</sub> > 1.1 V,			0.4	V
V <sub>OUT</sub>	Normal mode	I <sub>O</sub> = 8.5 mA, V <sub>BAT</sub> = 0 V	V <sub>DD</sub> = 1.8 V,	V <sub>DD</sub> -50 mV			V
		I <sub>O</sub> = 125 mA, V <sub>BAT</sub> = 0 V	V <sub>DD</sub> = 3.3 V,	V <sub>DD</sub> -150 mV			
		I <sub>O</sub> = 200 mA, V <sub>BAT</sub> = 0 V	V <sub>DD</sub> = 5 V,	V <sub>DD</sub> -200 mV			
	Battery-backup mode	I <sub>O</sub> = 0.5 mA, V <sub>BAT</sub> = 1.5 V	V <sub>DD</sub> = 0 V,	V <sub>BAT</sub> -20 mV			
		I <sub>O</sub> = 7.5 mA, V <sub>BAT</sub> = 3.3 V	V <sub>DD</sub> = 0 V,	V <sub>BAT</sub> -113 mV			

NOTE 3: The lowest supply voltage at which  $\overline{\text{RESET}}$  becomes active.  $t_r$ , V<sub>DD</sub> ≥ 15 μs/V



# TPS3610U18, TPS3610T50

## BATTERY-BACKUP SUPERVISORS FOR RAM RETENTION

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electrical characteristics over recommended operating free-air temperature range (unless otherwise noted) (continued)

PARAMETER		TEST CONDITIONS		MIN	TYP	MAX	UNIT
V <sub>IT</sub>	Negative-going input threshold voltage (see Note 4)	TPS3610U18	T <sub>A</sub> = -40°C to 85°C	1.68	1.71	1.74	V
		TPS3610T50		4.46	4.55	4.64	
V(PFI)		PFI		1.13	1.15	1.17	
V(BOK)		TPS3610T50		2.33	2.4	2.47	
		TPS3610U18		1.55	1.6	1.65	
V(LL)		LOWLINE			V <sub>IT</sub> +1.2%	V <sub>IT</sub> +2%	V <sub>IT</sub> +2.8%
V <sub>hys</sub>	Hysteresis	V <sub>IT</sub>	1.65 V < V <sub>IT</sub> < 2.5 V	20		mV	
			2.5 V < V <sub>IT</sub> < 3.5 V	40			
			3.5 V < V <sub>IT</sub> < 5.5 V	60			
		LOWLINE	1.65 V < V(LL) < 2.5 V	20			
			2.5 V < V(LL) < 3.5 V	40			
			3.5 V < V(LL) < 5.5 V	60			
		BAT TOK	1.65 V < V(BOK) < 2.5 V	20			
			2.5 V < V(BOK) < 3.5 V	40			
			3.5 V < V(BOK) < 5.5 V	60			
		PFI		12			
V <sub>BSW</sub> (see Note 5)	V <sub>DD</sub> = 1.8 V	55					
I <sub>IH</sub>	High-level input current	WDI	WDI = V <sub>DD</sub> = 5 V	150		μA	
I <sub>IL</sub>	Low-level input current	(see Note 6)	WDI = 0 V, V <sub>DD</sub> = 5 V	-150			
I <sub>I</sub>	Input current	PFI, MSWITCH		-25	25		nA
I <sub>OS</sub>	Short-circuit output current	PFO	PFO = 0 V	V <sub>DD</sub> = 1.8 V	-0.3		mA
				V <sub>DD</sub> = 3.3 V	-1.1		
				V <sub>DD</sub> = 5 V	-2.4		
I <sub>DD</sub>	Supply current at V <sub>DD</sub>	V <sub>OUT</sub> = V <sub>DD</sub>		40		μA	
		V <sub>OUT</sub> = V <sub>BAT</sub>		40			
I <sub>BAT</sub>	Supply current at V <sub>BAT</sub>	V <sub>OUT</sub> = V <sub>DD</sub>		-0.1	0.1		μA
		V <sub>OUT</sub> = V <sub>BAT</sub>		0.5			
I <sub>Ikg</sub>	Leakage current at $\overline{CEIN}$	Disable mode, V <sub>I</sub> < V <sub>DD</sub>		±1		μA	
r <sub>DS(on)</sub>	V <sub>DD</sub> to V <sub>OUT</sub> on-resistance	V <sub>DD</sub> = 5 V		0.6	1		Ω
	V <sub>BAT</sub> to V <sub>OUT</sub> on-resistance	V <sub>BAT</sub> = 3.3 V		8	15		
C <sub>i</sub>	Input capacitance	V <sub>I</sub> = 0 V to 5 V		5		pF	

- NOTES: 4. To ensure best stability of the threshold voltage, a bypass capacitor (ceramic, 0.1 μF) should be placed near to the supply terminals.  
5. For V<sub>DD</sub> < 1.6 V, V<sub>OUT</sub> switches to V<sub>BAT</sub> regardless of V<sub>BAT</sub>  
6. For details on how to optimize current consumption when using WDI. Refer to detailed description section, *watchdog*.



# TPS3610U18, TPS3610T50 BATTERY-BACKUP SUPERVISORS FOR RAM RETENTION

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timing requirements at  $R_L = 1\text{ M}\Omega$ ,  $C_L = 50\text{ pF}$ ,  $T_A = -40^\circ\text{C}$  to  $85^\circ\text{C}$

PARAMETER		TEST CONDITIONS	MIN	TYP	MAX	UNIT
$t_w$	Pulse width	At $V_{DD}$	$V_{IH} = V_{IT} + 0.2\text{ V}$ , $V_{IL} = V_{IT} - 0.2\text{ V}$	6		$\mu\text{s}$
		At $WDI$	$V_{DD} = V_{IT} + 0.2\text{ V}$ , $V_{IL} = 0.3 \times V_{DD}$ , $V_{IH} = 0.7 \times V_{DD}$	100		ns

switching characteristics at  $R_L = 1\text{ M}\Omega$ ,  $C_L = 50\text{ pF}$ ,  $T_A = -40^\circ\text{C}$  to  $85^\circ\text{C}$

PARAMETER		TEST CONDITIONS	MIN	TYP	MAX	UNIT
$t_d$	Delay time	$V_{DD} > V_{IT} + 0.2\text{ V}$	60	100	140	ms
$t_{(tout)}$	Watchdog timeout	(see timing diagram)	0.48	0.8	1.12	s
$t_{PLH}$	Propagation (delay) time, low-to-high-level output	50% $\overline{\text{RESET}}$ to 50% $\overline{\text{CEOUT}}$		15		$\mu\text{s}$
$t_{PHL}$	Propagation (delay) time, high-to-low-level output	$V_{DD} = 1.8\text{ V}$		5	15	ns
		$V_{DD} = 3.3\text{ V}$		1.6	5	
		$V_{DD} = 5\text{ V}$		1	3	
		$V_{DD}$ to $\overline{\text{RESET}}$	$V_{IL} = V_{IT} - 0.2\text{ V}$ , $V_{IH} = V_{IT} + 0.2\text{ V}$		2	5
PFI to $\overline{\text{PFO}}$	$V_{IL} = V(\text{PFI}) - 0.2\text{ V}$ , $V_{IH} = V(\text{PFI}) + 0.2\text{ V}$		3	5		
$t_t$	Transition time	$V_{DD}$ to $\overline{\text{BATTON}}$			3	$\mu\text{s}$

NOTE 7: Specified by design

## TYPICAL CHARACTERISTICS

### Table of Graphs

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TYPICAL CHARACTERISTICS

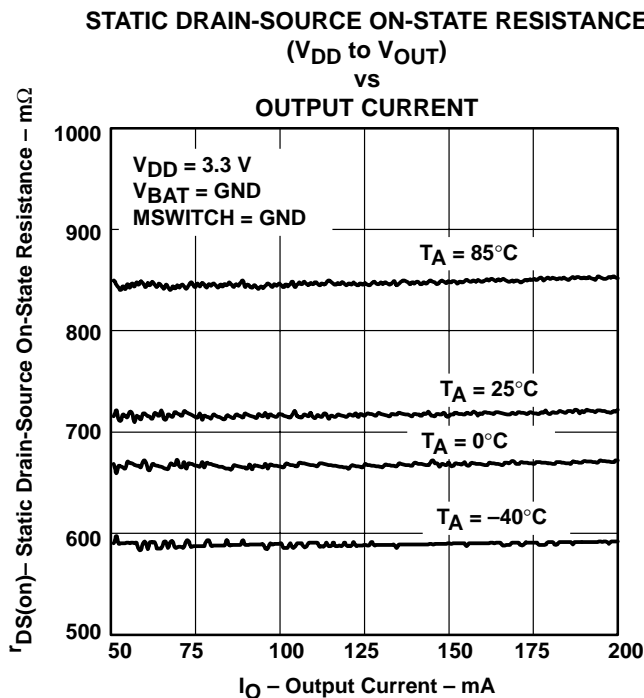


Figure 6

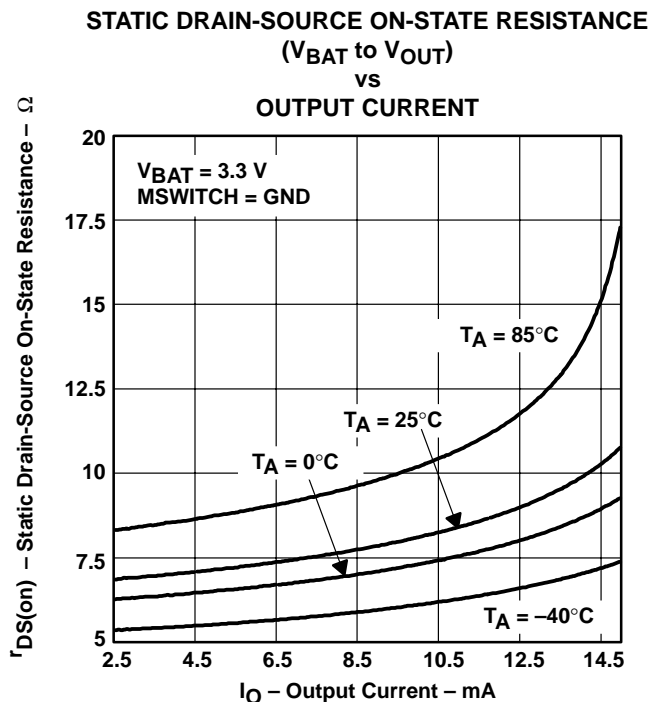


Figure 7

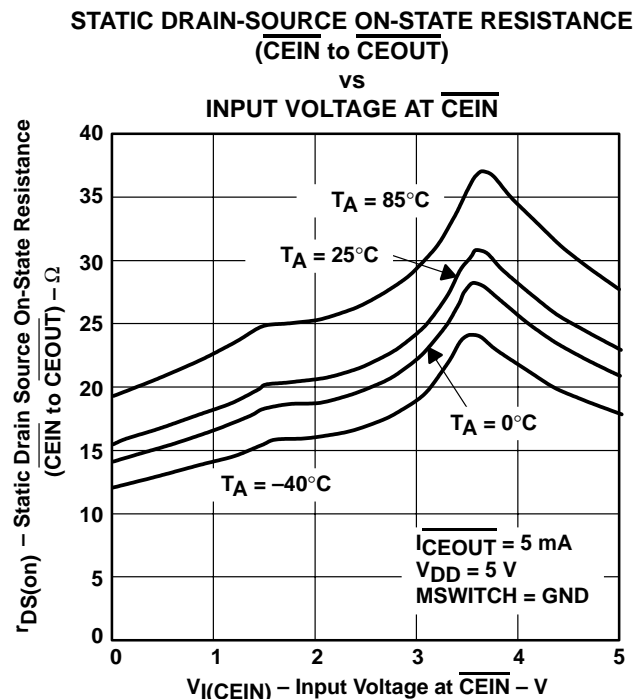


Figure 8

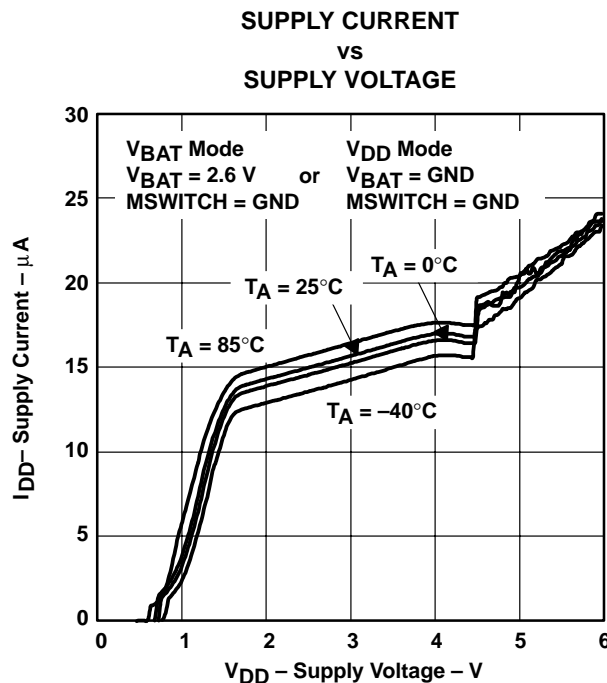


Figure 9

# TPS3610U18, TPS3610T50 BATTERY-BACKUP SUPERVISORS FOR RAM RETENTION

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## TYPICAL CHARACTERISTICS

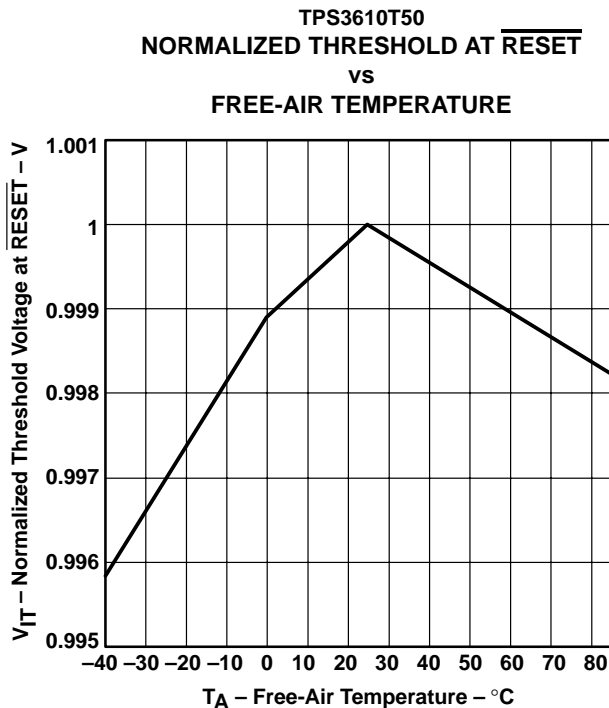


Figure 10

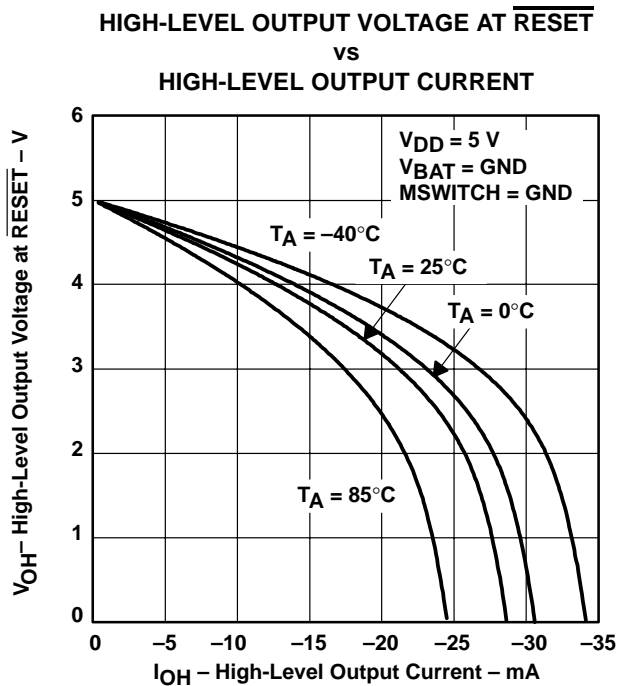


Figure 11

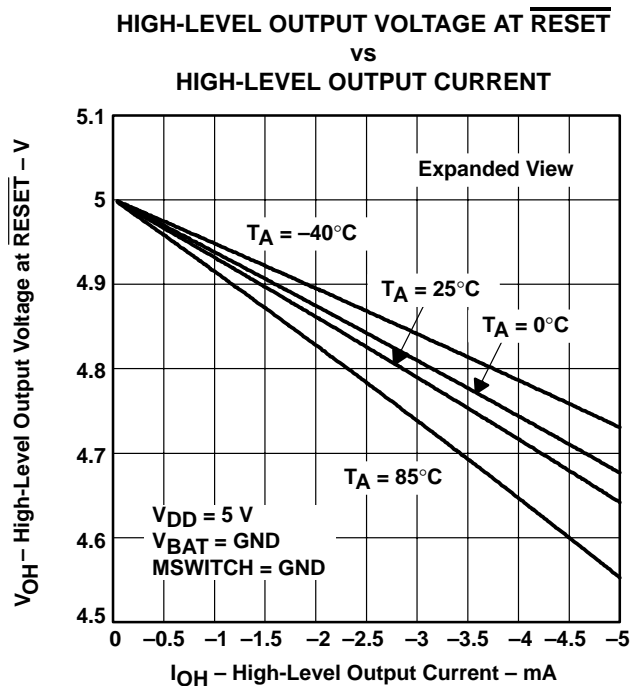


Figure 12





TYPICAL CHARACTERISTICS

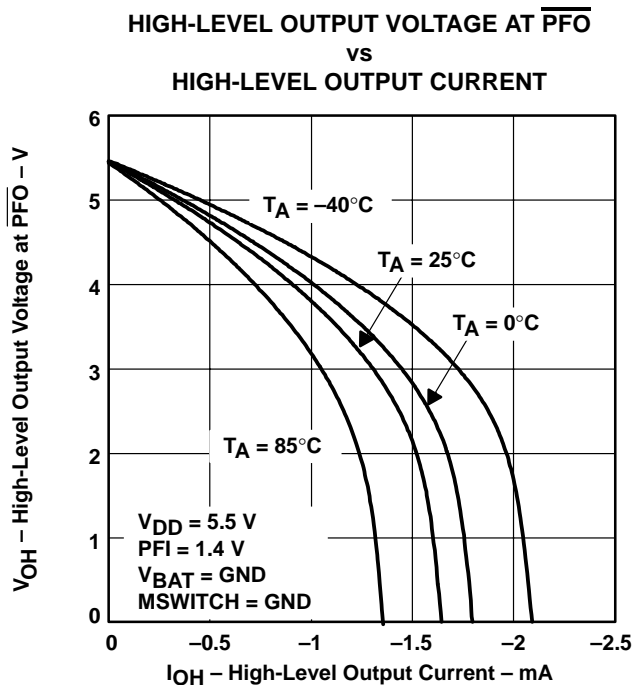


Figure 13

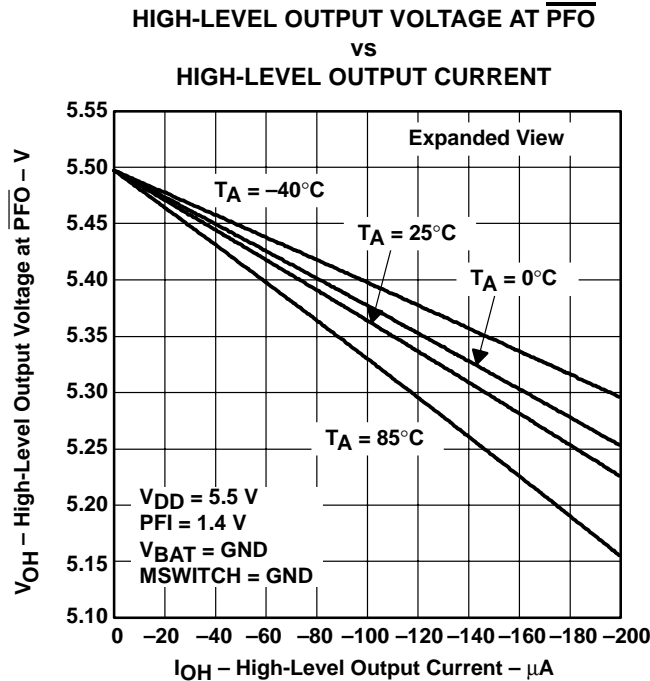


Figure 14

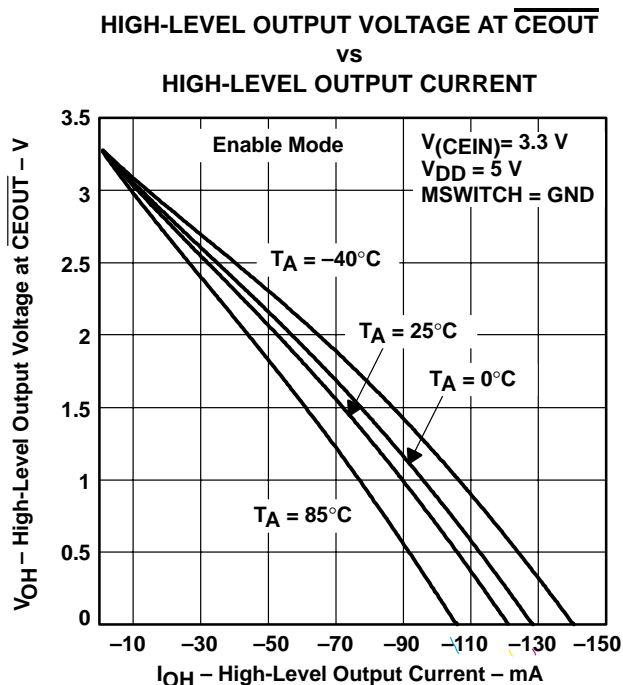


Figure 15

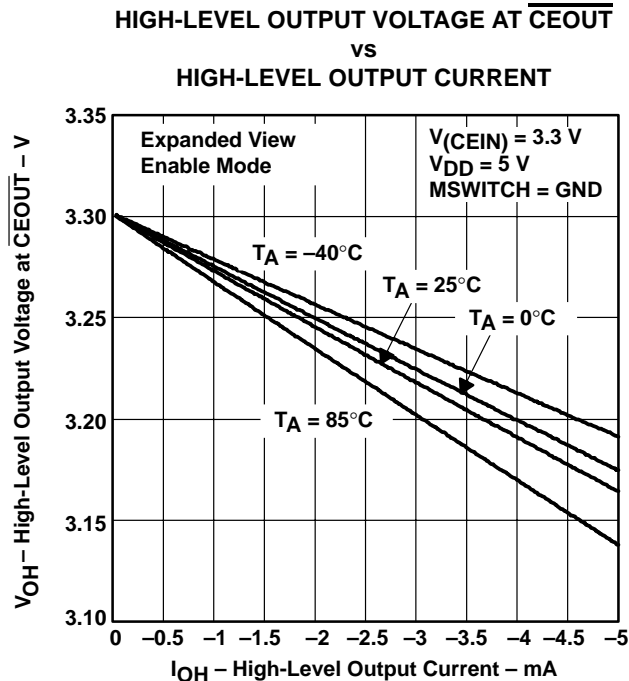
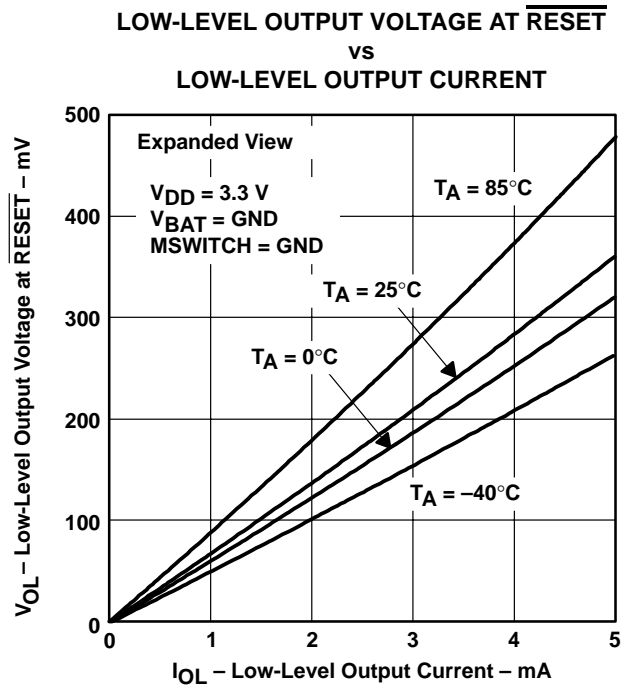
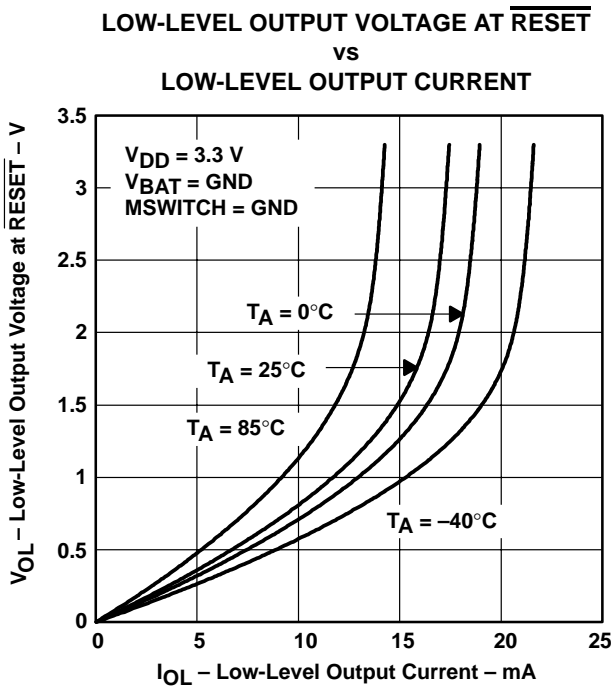
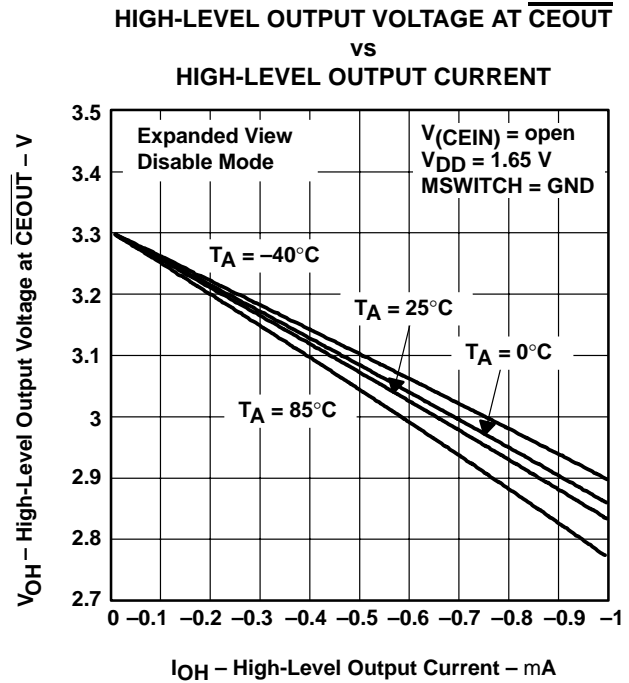
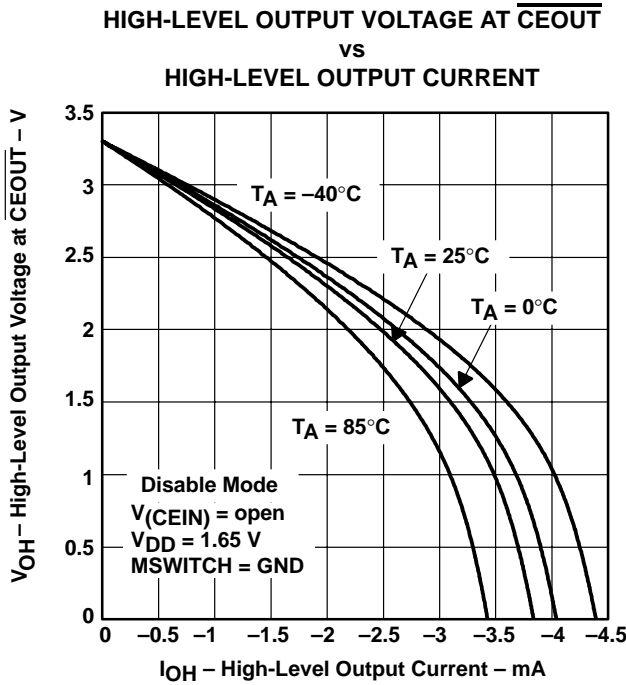


Figure 16

# TPS3610U18, TPS3610T50 BATTERY-BACKUP SUPERVISORS FOR RAM RETENTION

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## TYPICAL CHARACTERISTICS



TYPICAL CHARACTERISTICS

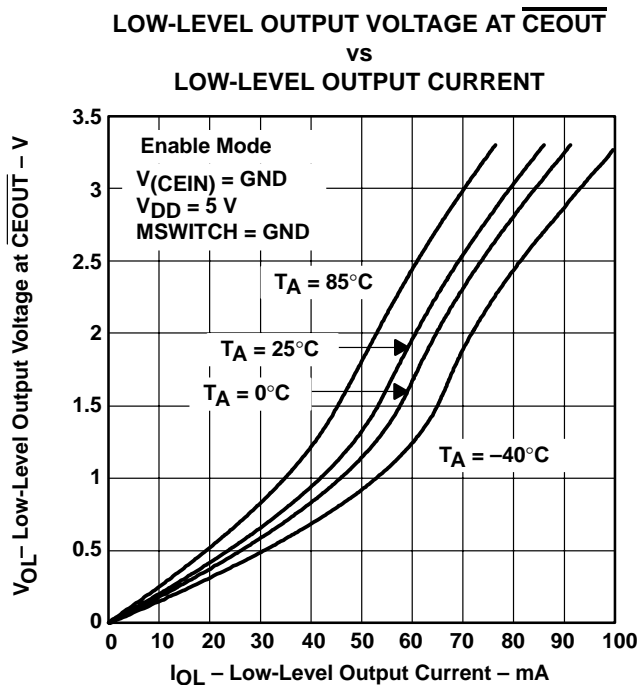


Figure 21

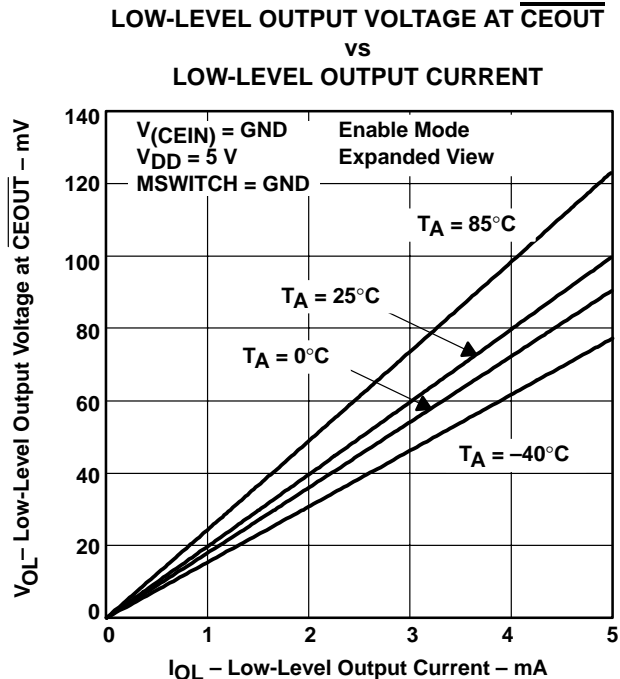


Figure 22

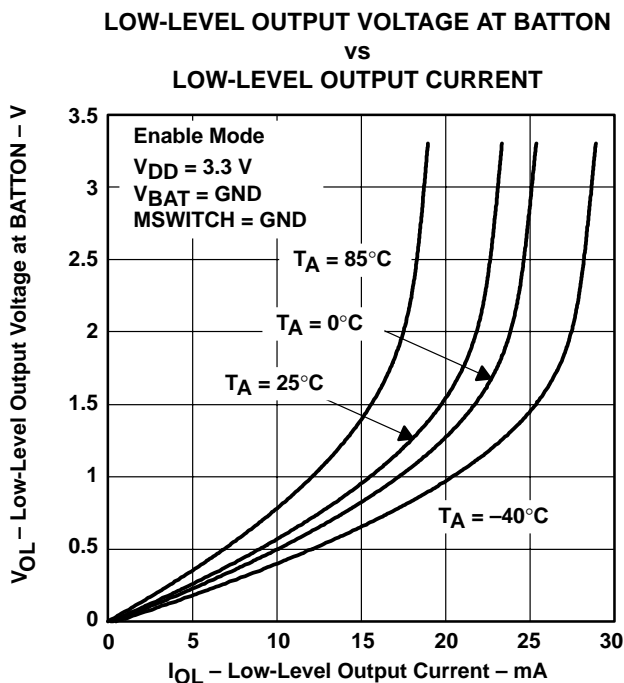


Figure 23

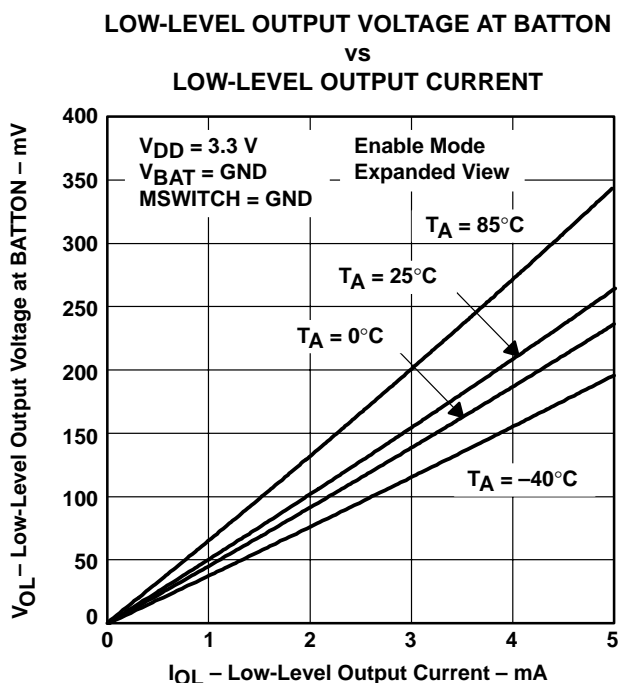


Figure 24

# TPS3610U18, TPS3610T50 BATTERY-BACKUP SUPERVISORS FOR RAM RETENTION

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## TYPICAL CHARACTERISTICS

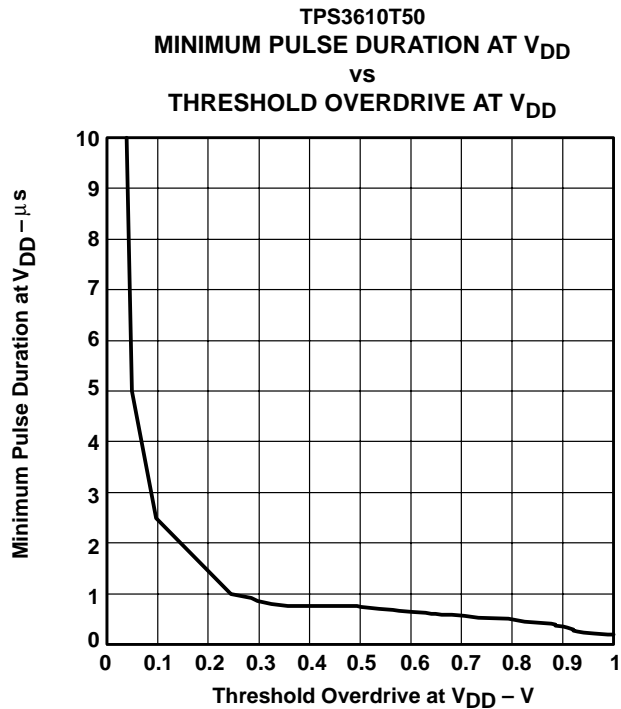


Figure 25

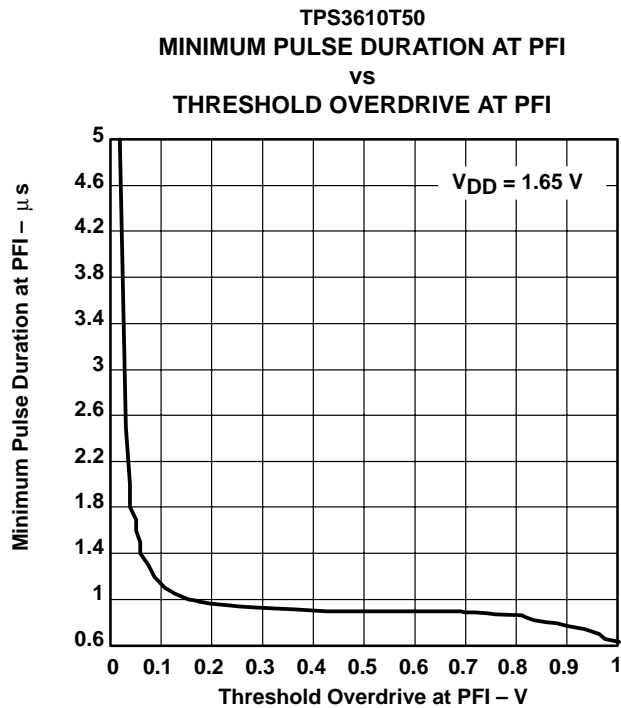


Figure 26



# TPS3610U18, TPS3610T50 BATTERY-BACKUP SUPERVISORS FOR RAM RETENTION

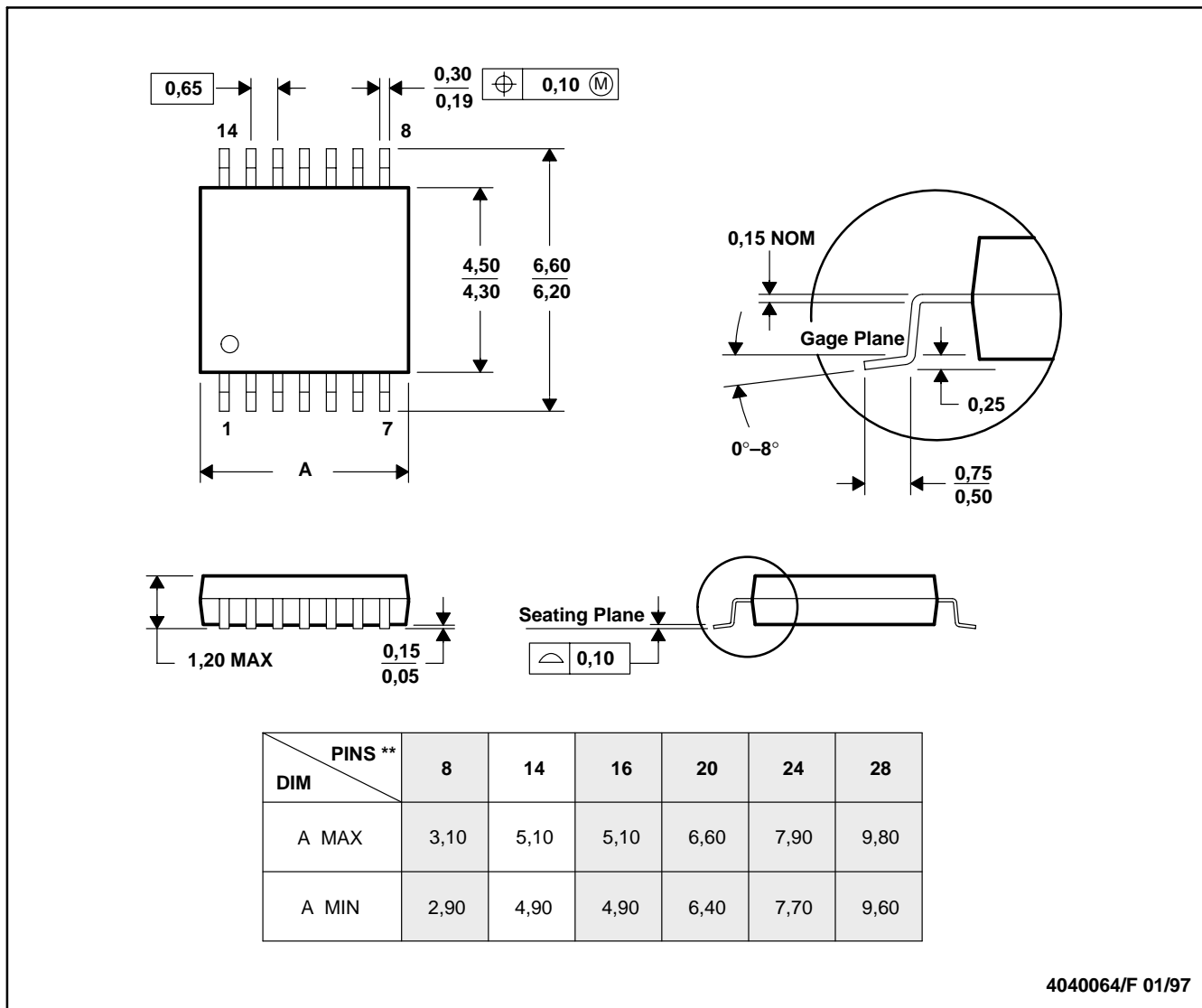
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## MECHANICAL DATA

**PW (R-PDSO-G\*\*)**

**PLASTIC SMALL-OUTLINE PACKAGE**

14 PINS SHOWN



- NOTES: A. All linear dimensions are in millimeters.  
 B. This drawing is subject to change without notice.  
 C. Body dimensions do not include mold flash or protrusion not to exceed 0,15.  
 D. Falls within JEDEC MO-153

**PACKAGING INFORMATION**

Orderable Device	Status <sup>(1)</sup>	Package Type	Package Drawing	Pins	Package Qty	Eco Plan <sup>(2)</sup>	Lead/Ball Finish	MSL Peak Temp <sup>(3)</sup>
TPS3610T50PW	ACTIVE	TSSOP	PW	14	90	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
TPS3610T50PWG4	ACTIVE	TSSOP	PW	14	90	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
TPS3610T50PWR	ACTIVE	TSSOP	PW	14	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
TPS3610T50PWRG4	ACTIVE	TSSOP	PW	14	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
TPS3610U18PW	ACTIVE	TSSOP	PW	14	90	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
TPS3610U18PWG4	ACTIVE	TSSOP	PW	14	90	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
TPS3610U18PWR	ACTIVE	TSSOP	PW	14	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
TPS3610U18PWRG4	ACTIVE	TSSOP	PW	14	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM

<sup>(1)</sup> The marketing status values are defined as follows:

**ACTIVE:** Product device recommended for new designs.

**LIFEBUY:** TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.

**NRND:** Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.

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**OBSOLETE:** TI has discontinued the production of the device.

<sup>(2)</sup> Eco Plan - The planned eco-friendly classification: Pb-Free (RoHS), Pb-Free (RoHS Exempt), or Green (RoHS & no Sb/Br) - please check <http://www.ti.com/productcontent> for the latest availability information and additional product content details.

**TBD:** The Pb-Free/Green conversion plan has not been defined.

**Pb-Free (RoHS):** TI's terms "Lead-Free" or "Pb-Free" mean semiconductor products that are compatible with the current RoHS requirements for all 6 substances, including the requirement that lead not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, TI Pb-Free products are suitable for use in specified lead-free processes.

**Pb-Free (RoHS Exempt):** This component has a RoHS exemption for either 1) lead-based flip-chip solder bumps used between the die and package, or 2) lead-based die adhesive used between the die and leadframe. The component is otherwise considered Pb-Free (RoHS compatible) as defined above.

**Green (RoHS & no Sb/Br):** TI defines "Green" to mean Pb-Free (RoHS compatible), and free of Bromine (Br) and Antimony (Sb) based flame retardants (Br or Sb do not exceed 0.1% by weight in homogeneous material)

<sup>(3)</sup> MSL, Peak Temp. -- The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.

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**TAPE AND REEL INFORMATION**



**QUADRANT ASSIGNMENTS FOR PIN 1 ORIENTATION IN TAPE**



\*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Reel Diameter (mm)	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
TPS3610T50PWR	TSSOP	PW	14	2000	330.0	12.4	7.0	5.6	1.6	8.0	12.0	Q1
TPS3610U18PWR	TSSOP	PW	14	2000	330.0	12.4	7.0	5.6	1.6	8.0	12.0	Q1

**TAPE AND REEL BOX DIMENSIONS**



\*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Length (mm)	Width (mm)	Height (mm)
TPS3610T50PWR	TSSOP	PW	14	2000	340.5	338.1	20.6
TPS3610U18PWR	TSSOP	PW	14	2000	340.5	338.1	20.6



PW (R-PDSO-G\*\*)

PLASTIC SMALL-OUTLINE PACKAGE

14 PINS SHOWN



4040064/F 01/97

- NOTES: A. All linear dimensions are in millimeters.  
 B. This drawing is subject to change without notice.  
 C. Body dimensions do not include mold flash or protrusion not to exceed 0,15.  
 D. Falls within JEDEC MO-153

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